

FEATURES

- * 0.56 inch (14.22 mm) DIGIT HEIGHT.
- * CONTINUOUS UNIFORM SEGMENTS.
- * LOW POWER REQUIREMENT.
- * EXCELLENT CHARACTERS APPEARANCE.
- * HIGH BRIGHTNESS & HIGH CONTRAST.
- * WIDE VIEWING ANGLE.
- * SOLID STATE RELIABILITY.

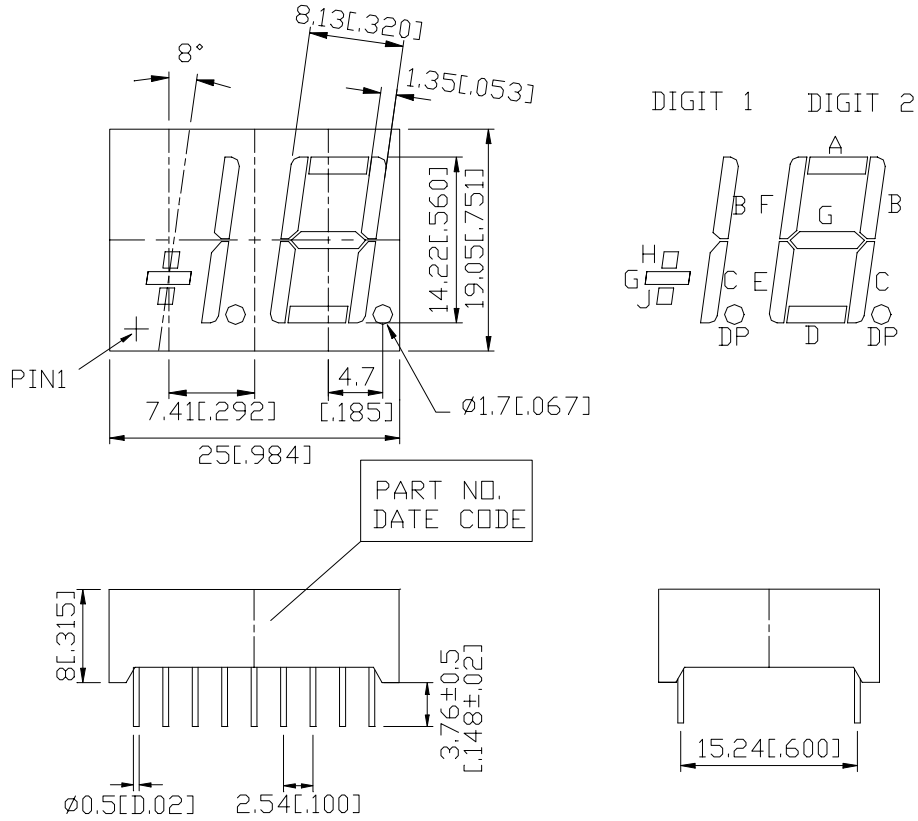
DESCRIPTION

The LTD-6630E is a 0.56 inch (14.22 mm) height digit display. This device utilizes red orange LED chips, which are made from GaAsP on a transparent GaP substrate, and has a orange face and orange segments.

DEVICE

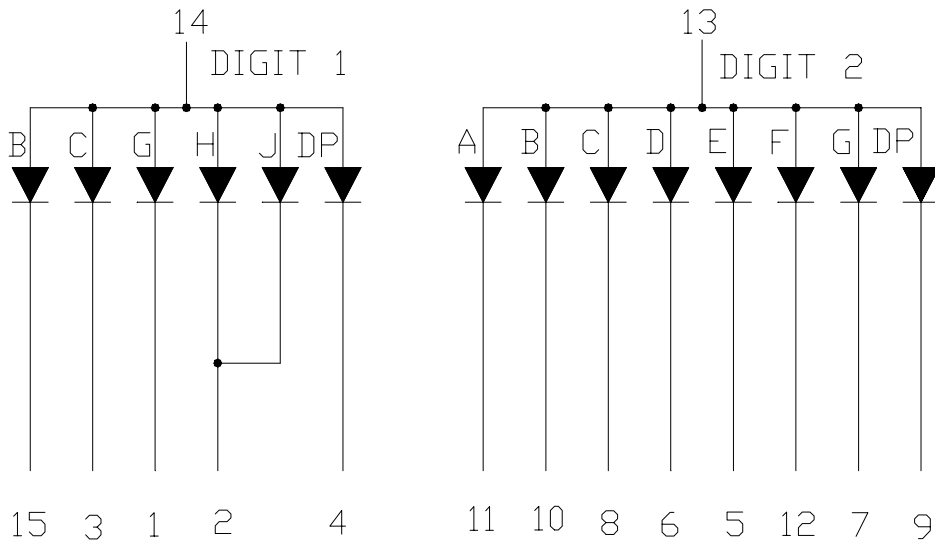
PART NO.	DESCRIPTION
Red Orange	Common Anode ±1.8 Overflow
LTD-6630E	

PACKAGE DIMENSIONS



NOTES: All dimensions are in millimeters. Tolerances are ± 0.25 mm (0.01“) unless otherwise noted.

INTERNAL CIRCUIT DIAGRAM



PIN CONNECTION

NO.	CONNECTION
1	Cathode G (Digit 1)
2	Cathode J.H (Digit 1)
3	Cathode C (Digit1)
4	Cathode D.P. (Digit 1)
5	Cathode E (Digit 2)
6	Cathode D (Digit 2)
7	Cathode G (Digit 2)
8	Cathode C (Digit 2)
9	Cathode D.P. (Digit 2)
10	Cathode B (Digit 2)
11	Cathode A (Digit 2)
12	Cathode F (Digit2)
13	Common Anode (Digit 2)
14	Common Anode (Digit 1)
15	Cathode B (Digit 1)
16	No Connection
17	No Connection
18	No Connection

ABSOLUTE MAXIMUM RATING AT Ta=25°C

PARAMETER	MAXIMUM RATING	UNIT
Power Dissipation Per Segment	75	mW
Peak Forward Current Per Segment (1/10 Duty Cycle, 0.1ms Pulse Width)	100	mA
Continuous Forward Current Per Segment Derating Linear From 25°C Per Segment	25 0.33	mA mA/°C
Reverse Voltage Per Segment	5	V
Operating Temperature Range	-35°C to +85°C	
Storage Temperature Range	-35°C to +85°C	
Solder Temperature: max 260°C for max 3sec at 1.6mm below seating plane.		

ELECTRICAL / OPTICAL CHARACTERISTICS AT Ta=25°C

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	I _v	800	2400		μcd	I _F =10mA
Peak Emission Wavelength	λ _p		630		nm	I _F =20mA
Spectral Line Half-Width	Δλ		40		nm	I _F =20mA
Dominant Wavelength	λ _d		621		nm	I _F =20mA
Forward Voltage Per Segment	V _F		2.0	2.6	V	I _F =20mA
Reverse Current Per Segment	I _R			100	μA	V _R =5V
Luminous Intensity Matching Ratio	I _v -m			2:1		I _F =10mA

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

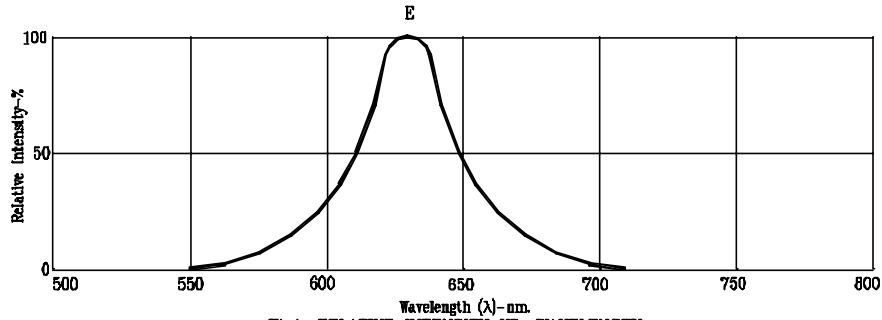


Fig1. RELATIVE INTENSITY VS. WAVELENGTH

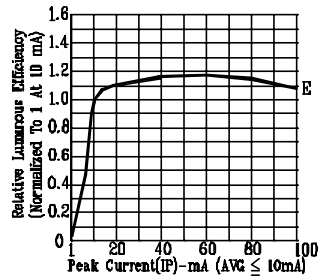


Fig2. RELATIVE LUMINOUS EFFICIENCY (LUMINOUS INTENSITY PER UNIT CURRENT) VS. PEAK CURRENT (REFRESH RATE 1KHz)

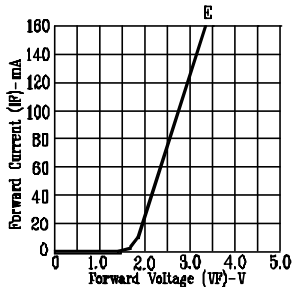


Fig3. FORWARD CURRENT VS. FORWARD VOLTAGE

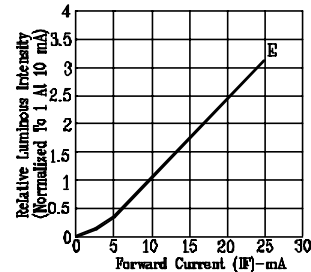


Fig4. RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT

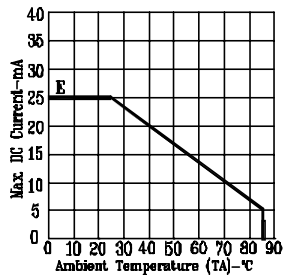


Fig5. MAX ALLOWABLE DC CURRENT VS. AMBIENT TEMPERATURE.

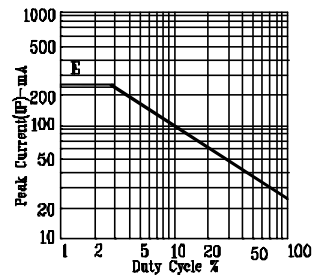


Fig6. MAX. PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE 1KHz)

NOTE: E=RED ORANGE